AMENDMENTS TO THE CLAIMS

1-28. (Canceled)

29. (New) An implantable amplifying circuit for recording signals generated by a

nerve and detected by a pair of electrode wires in contact with the nerve, the amplifying circuit

comprising:

a preamplifier having a pair of inputs for receiving signals from electrode wires, the

preamplifier including a differential pair of input MOSFET transistors having a low input current

that serves as a first input protection circuit to limit current flow through the nerve and the

electrode wires;

a common signal line that is coupleable to the nerve;

a second input protection circuit disposed in series with the common signal line including

a parallel resistor/capacitor combination to limit current flow through the nerve and the common

signal line.

30. (New) The implantable amplifying circuit of claim 29, wherein the preamplifier

includes a pair of bipolar transistors and a current mirror that are driven with differential outputs

of the MOSFET input transistors and produces a single-ended nerve output signal.

31. (New) The implantable amplifying circuit of claim 29, wherein said second input

protection circuit comprises a resistor in parallel with a series of one or more capacitors, said

parallel pair connected between the common signal line connectable to the nerve and a reference

voltage terminal that provides a virtual ground terminal in respect of said implantable amplifying

circuit.

32. (New) The implantable amplifying circuit of claim 29, further comprising:

at least one amplifier stage connected to an output at the preamplifier that produces an

amplified nerve output signal.

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33. (New) The implantable amplifying circuit of claim 32, further comprising a DC restoration circuit having an input connected to an output of said amplifier stage.

34. (New) The implantable amplifying circuit of claim 32, wherein said amplifier stage is a band-pass amplifier.

35. (New) The implantable amplifying circuit of claim 34, wherein said band-pass amplifier comprises a plurality of high-pass filters and a plurality of low-pass negative-feedback amplifiers alternatingly cascaded with said high-pass filters.

36. (New) The implantable amplifying circuit of claim 34, wherein said band-pass amplifier is a programmable-gain band-pass amplifier.

37. (New) The implantable amplifying circuit of claim 35, wherein each low-pass negative-feedback amplifier comprises:

a plurality of series-connected resistors forming a resistor string connected between an output terminal and a voltage reference terminal of the low-pass negative-feedback amplifier; and

a plurality of selectable switches wherein an end of each selectable switch is connected to an input terminal of the low-pass negative-feedback amplifier and another end of each selectable switch is connected to a nodal point between the resistors in the resistor string.

38. (New) The implantable amplifying circuit of claim 35, wherein each low-pass negative-feedback amplifier comprises an output stage in a Darlington configuration operating as a class AB amplifier wherein a bias circuit supplying bias to the output stage also carries signal current.

39. (New) The implantable amplifying circuit of claim 36, wherein said programmable-gain band-pass amplifier has a frequency range between approximately 900 Hz and 9 kHz for 5 μ V_{peak} input neural signals.

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- 40. (New) The implantable amplifying circuit of claim 29, wherein the implantable amplifying circuit has an equivalent input noise at 3 kHz that is lower than 0.6 μV_{rms} .
- 41. (New) The implantable amplifying circuit of claim 29, wherein the implantable amplifying circuit has a CMRR higher than 90 dB at 250 Hz.
- 42. (New) The implantable amplifying circuit of claim 29, wherein the implantable amplifying circuit has a power consumption lower than 12 mW.
- 43. (New) The implantable amplifying circuit of claim 29, wherein the preamplifier has an input DC current that is lower than 1 nanoamp.
- 44. (New) The implantable amplifying circuit of claim 29, wherein said implantable amplifying circuit is powered by an RF telemetry link.
- 45. (New) The implantable amplifying circuit of claim 29, wherein the implantable amplifying circuit has a PSRR higher than 85 dB at 3 kHz.
- 46. (New) The implantable amplifying circuit of claim 29, wherein said implantable amplifying circuit is powered by a battery.